



As a below named inventor, I hereby declare that:

Post Office Address: Same as Above

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled: SELF-ALIGNED DOUBLE-GATE MOSFET BY SELECTIVE EPITAXY AND SILICON WAFER BONDING TECHNIQUES

	the specification of which: (check one)					
	is attached hereto.□ was filed on	_, as Application Serial No.	and	d was amended on		
	I hereby state that I have reviewed and understand amendment referred to above.	d the contents of the above i	dentified specification, inc	cluding the claims, as amended by any		
	I acknowledge the duty to disclose information we Federal Regulations, § 1.56.	hich is material to the pater	tability of this application	in accordance with Title 37, Code of		
# 1 #	Prior Foreign Application(s):	•				
r T	Number . Cou	untry	Day/Month/Year	Priority Claimed		
_	I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, § 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:					
	Prior U.S. Applications:			-		
<u></u>	Serial No. Filing D	ate	Status			
,	I hereby declare that all statements made herein of my own knowledge are true arid that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Tide 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.					
	POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorneys and/or agents to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration number). Manny W. Schecter (Reg. 31,722), Terry J. Ilardi (Reg. 29,936), Christopher A. Hughes (Reg. 26,914), Edward A. Pennington (Reg. 32,588), John E. Hoel (Reg. 26,279), Joseph C. Redmond, Jr., (Reg. 18,753), Douglas W. Cameron (Reg. 31,596), Kevin M. Jordan (Reg. 40,277), Stephen C. Kaufman (Reg. 29,551), Jay P. Sbrollini (Reg. No. 36,266), David M. Shofi (Reg. 39,835), Robert M. Trepp (Reg. 25,933), Louis P. Herzberg (Reg. 41,500), Daniel Morris (Reg. 32,053) and Louis J. Percello (Reg. 33,206). Send all correspondence to: Frederick W. Gibb, III, Esq. McGinn & Gibb, P.C., 1701 Clarendon Boulevard, Suite 100, Arlington, Virginia 22209. Cust. No. 21254 Telephone calls should be directed to McGinn & Gibb, P.C. at (703) 294-6699.					
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